

## PART NUMBER 5041^BEA

# Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

### **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
  - Class Q Military
  - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

INCH-POUND
MIL-M-38510/105A
23 January 2006
SUPERSEDING
MIL-M-38510/105
23 December 1980

### MILITARY SPECIFICATION

MICROCIRCUITS, LINEAR, CMOS, HIGH LEVEL ANALOG SWITCH WITH DRIVER, MONOLITHIC SILICON

This specification is approved for use by all Departments and Agencies of the Department of Defense.

Inactive for new design after 10 July 1995.

The requirement for acquiring the product herein shall consist of this specification sheet and MIL-PRF-38535.

- 1. SCOPE
- 1.1 <u>Scope.</u> This specification covers the detail requirements for silicon, CMOS, monolithic, analog switches. Two product assurance classes and a choice of case outlines and lead finishes are provided and are reflected in the complete part number. For this product, the requirements of MIL-M-38510 have been superseded by MIL-PRF-38535, (see 6.4)
  - 1.2 Part or Identifying Number (PIN). The PIN is in accordance with MIL-PRF-38535, and as specified herein.
  - 1.2.1 Device types. The device types are as follows:

Device type	<u>Circuit</u>
01	One-channel, 75 ohm, SPST switch
02	Two-channel, 75 ohm, SPST switch
03	One-channel, 75 ohm, SPDT switch
04	Two-channel, 75 ohm, SPDT switch
05	One-channel, 75 ohm, DPST switch
06	Two-channel, 75 ohm, DPST switch
07	One-channel, 75 ohm, DPDT switch
80	One-channel, 75 ohm, 4PST switch

NOTE: A channel is defined as a driver with associated switches.

- 1.2.2 <u>Device class</u>. The device class is the product assurance level as defined in MIL-PRF-38535.
- 1.2.3 Case outline. The case outlines are as designated in MIL-STD-1835 and as follows:

Outline letter	Descriptive designator	<u>Terminals</u>	Package style
A <u>1</u> /	GDFP5-F14 or CDFP6-F14	14	Flat pack
E	GDIP1-T16 or CDIP2-T16	16	Dual-in-line
I	MACY1-X10	10	Can

Inactive for new design. Acceptable only for use in equipment designed or redesigned on or before 29 November 1986.

Comments, suggestions, or questions on this document should be addressed to: Commander, Defense Supply Center Columbus, ATTN: DSCC-VAS, 3990 East Broad St., Columbus, OH 43218-3990, or email <a href="mailto:linear@dscc.dla.mil">linear@dscc.dla.mil</a>. Since contact information can change, you may want to verify the currency of this address information using the ASSIST Online database at <a href="http://assist.daps.dla.mil">http://assist.daps.dla.mil</a>.

AMSC N/A FSC 5962

### MIL-M-38510/105A

### 1.3 Absolute maximum ratings.

V+ - V	33 V dc
V+ - V <sub>D</sub>	30 V dc
V <sub>D</sub> - V	30 V dc
V <sub>D</sub> - V <sub>S</sub>	±22 V dc
V <sub>L</sub> – V	33 V dc
V <sub>L</sub> – V <sub>IN</sub>	30 V dc
V <sub>L</sub> – V <sub>R</sub>	20 V dc
V <sub>IN</sub> – V <sub>R</sub>	20 V dc
V <sub>R</sub> – V	33 V dc
V <sub>R</sub> - V <sub>IN</sub>	30 mA -65°C to +150°C +300°C
+VCC	
-V <sub>CC</sub>	-15 V dc

### 1.5 Power and thermal characteristics.

1.4

Case outline	Maximum allowable power dissipation <u>2</u> /	Maximum θ <sub>JC</sub> <u>3</u> /	Maximum θ <sub>JA</sub>
Α	350 mW at T <sub>A</sub> = 125°C	60°C/W	140°C/W
Е	400 mW at T <sub>A</sub> = 125°C	35°C/W	120°C/W
I	350 mW at T <sub>A</sub> = 125°C	40°C/W	140°C/W

<sup>2/</sup> All leads welded or soldered to PC board.

 $<sup>\</sup>underline{3}/\quad \text{ Applies only when } T_A \geq 75^{\circ}C.$ 

#### 2. APPLICABLE DOCUMENTS

- 2.1 <u>General</u>. The documents listed in this section are specified in sections 3, 4, or 5 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements of documents cited in sections 3, 4, or 5 of this specification, whether or not they are listed.
- 2.1.1 <u>Specifications, standards, and handbooks</u>. The following specifications and standards form a part of this specification to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

### DEPARTMENT OF DEFENSE SPECIFICATIONS

MIL-PRF-38535 - Integrated Circuits (Microcircuits) Manufacturing, General Specification for.

### DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-883 - Test Method Standard for Microelectronics.

MIL-STD-1835 - Interface Standard Electronic Component Case Outlines.

(Copies of these documents are available online at <a href="http://assist.daps.dla.mil/quicksearch/">http://assist.daps.dla.mil/quicksearch/</a> or <a href="http://assist.daps.dla.mil">http://assist.daps.dla.mil</a> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.

2.2 <u>Order of precedence</u>. In the event of a conflict between the text of this specification and the references cited herein the text of this document shall take precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

#### 3. REQUIREMENTS

- 3.1 <u>Qualification</u>. Microcircuits furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers list before contract award (see 4.3 and 6.3).
- 3.2 <u>Item requirements</u>. The individual item requirements shall be in accordance with MIL-PRF-38535 and as specified herein or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not affect the form, fit, or function as described herein.
- 3.3 <u>Design, construction, and physical dimensions</u>. The design, construction, and physical dimensions shall be as specified in MIL-PRF-38535 and herein.
- 3.3.1 <u>Circuit diagram and terminal connections.</u> The circuit diagram and terminal connections shall be as specified on figure 1.
- 3.3.2 <u>Schematic circuits</u>. The schematic circuits shall be maintained by the manufacturer and made available to the qualifying activity and the preparing activity upon request.
  - 3.3.4 <u>Case outlines.</u> The case outlines shall be as specified in 1.2.3.
  - 3.4 Lead material and finish. The lead material and finish shall be in accordance with MIL-PRF-38535 (see 6.6).
- 3.5 <u>Electrical performance characteristics</u>. The electrical performance characteristics are as specified in table I, and apply over the full recommended ambient operating temperature range, unless otherwise specified.

3.5.1 <u>Switch operation</u>. The analog switches listed below are guaranteed to turn "on" with either a "low" input ( $V_R \le V_{IL} \le 0.8 \text{ V}$ ) or "high" input (2.4 V  $\le V_{IH} \le V_{IL}$ ) as specified below (see figure 1).

Device types	VIN	Chann	els ON	Channe	els OFF		
01	2.4 V dc		I				
	0.8 V dc			1	1		
02, 05, 03	2.4 V dc	1, 2	1		2		
	0.8 V dc		2	1, 2	1		
04	2.4 V dc	1,	2	3,	4		
	0.8 V dc	3,	4	1,	2		
07	2.4 V dc	2,	3	1,	4		
	0.8 V dc	1,	4	2,	3		
06, 08	2.4 V dc	1, 2,	3, 4				
	0.8 V dc			1, 2, 3, 4			

<sup>3.6 &</sup>lt;u>Electrical test requirements</u>. Electrical test requirements for each device class shall be the subgroups specified in table II. The electrical tests for each subgroup are described in table III.

<sup>3.7</sup> Marking. Marking shall be in accordance with MIL-PRF-38535.

<sup>3.8 &</sup>lt;u>Microcircuit group assignment</u>. The devices covered by this specification shall be in microcircuit group number 82 (see MIL-PRF-38535, appendix A).

### MIL-M-38510/105A

TABLE I. Electrical performance characteristics.

Characteristic	Symbol	Conditions $V_{CC} = \pm 15 \text{ V, GND} = 0 \text{ V}$	Temperature range	Device type	Lir	Unit	
		unless otherwise specified			Min	Max	
Drain-source ON resistance	R <sub>DS</sub>	$V_D = -10 \text{ V}, \text{ I}_S = 10 \text{ mA},$	T <sub>A</sub> = -55°C, 25°C	All		75	Ω <u>1</u> /
resistance		see figure 2	T <sub>A</sub> = 125°C			150	
		$V_D = 10 \text{ V}, \text{ I}_S = -10 \text{ mA},$	T <sub>A</sub> = -55°C, 25°C	All		75	
		see figure 2	T <sub>A</sub> = 125°C			150	
		$V_D = -7.5 \text{ V}, V_{CC} = \pm 10 \text{ V},$	T <sub>A</sub> = -55°C, 25°C	All		75	
		I <sub>S</sub> = 10 mA, see figure 2	T <sub>A</sub> = 125°C			150	
		$V_D = 7.5 \text{ V}, V_{CC} = \pm 10 \text{ V},$	T <sub>A</sub> = -55°C, 25°C	All		75	
		I <sub>S</sub> = -10 mA, see figure 2	T <sub>A</sub> = 125°C	] /"		150	
Channel ON leakage current	I <sub>D(ON)</sub>	$V_S = V_D = 10 \text{ V},$ (see 3.5.1 for $V_{IN}$ ),	T <sub>A</sub> = -55°C, 125°C	All	-200	200	nA
		see figure 3	T <sub>A</sub> = 25°C		-2	+2	
		$V_S = V_D = -10 \text{ V},$	T <sub>A</sub> = -55°C, 125°C	- All	-200	200	
		( see 3.5.1 for V <sub>IN</sub> ), see figure 3	T <sub>A</sub> = 25°C	All	-2	+2	
Drain OFF leakage current	I <sub>D(OFF)</sub>	$V_D = 10 \text{ V}, V_S = -10 \text{ V},$	T <sub>A</sub> = -55°C, 125°C		-100	100	nA
		( see 3.5.1 for V <sub>IN</sub> ), see figure 4	T <sub>A</sub> = 25°C	All	-1	+1	_
		$V_D = -10 \text{ V}, V_S = 10 \text{ V},$ (see 3.5.1 for $V_{IN}$ ),	T <sub>A</sub> = -55°C, 125°C	All	-100	100	
		See figure 4	T <sub>A</sub> = 25°C		-1	+1	
Source OFF leakage current	I <sub>S(OFF)</sub>	$V_D = -10 \text{ V}, V_S = 10 \text{ V},$	T <sub>A</sub> = -55°C, 125°C	All	-100	100	nA
		( see 3.5.1 for V <sub>IN</sub> ), see figure 5	T <sub>A</sub> = 25°C	All	-1	+1	
		$V_D = 10 \text{ V}, V_S = -10 \text{ V},$	T <sub>A</sub> = -55°C, 125°C		-100	100	
		( see 3.5.1 for V <sub>IN</sub> ), see figure 5	T <sub>A</sub> = 25°C	All	-1	+1	
Input current, input voltage low	I <sub>IL</sub>	V <sub>IN</sub> = 0 V, see figure 6	T <sub>A</sub> = -55°C, 25°C	All	-1	0	μА
			T <sub>A</sub> = 125°C		-10	0	
Input current, input	liH	V <sub>IN</sub> = 2.4 V, 5 V,	T <sub>A</sub> = -55°C, 25°C	All	0	1	μА
voltage high		see figure 6	T <sub>A</sub> = 125°C		0	10	

### MIL-M-38510/105A

TABLE I. <u>Electrical performance characteristics</u> – Continued.

Tank	C: make al	Conditions	Temperature	Device	Lir	Unit	
Test	Symbol	V <sub>CC</sub> = ±15 V, GND = 0 V unless otherwise specified	range	type	Min	Max	-
Positive supply		V <sub>IN</sub> = 0 V, 5 V	T <sub>A</sub> = -55°C, 25°C	All		10	μА
current	+lcc	see figure 7	T <sub>A</sub> = 125°C	-		100	_
Negative supply		V <sub>IN</sub> = 0 V, 5 V	T <sub>A</sub> = -55°C, 25°C	All	-10		μА
current	-lcc	see figure 7	T <sub>A</sub> = 125°C		-100		
Logic supply current	+1_	V <sub>IN</sub> = 0 V, 5 V, see figure 7	T <sub>A</sub> = -55°C, 25°C	All		10	μА
			T <sub>A</sub> = 125°C			100	
Reference supply current	+I <sub>R</sub>	V <sub>IN</sub> = 0 V, 5 V, see figure 7	T <sub>A</sub> = -55°C, 25°C	All	-10		μА
			T <sub>A</sub> = 125°C		-100		
			T <sub>A</sub> = -55°C	All		375	ns
Turn ON time	toN	See figure 8	T <sub>A</sub> = 25°C	1		450	1
			T <sub>A</sub> = 125°C	1		550	1
Town OFF times	4	See figure 8	T <sub>A</sub> = -55°C	All		250	ns
Turn OFF time	tOFF	See ligure o	T <sub>A</sub> = 25°C	1		250	1
			T <sub>A</sub> = 125°C	1		400	1
Single channel isolation	V <sub>ISO</sub>	f = 1 MHz , V <sub>GEN</sub> = 1 V <sub>P-P</sub> , see figure 9	T <sub>A</sub> = 25°C	All	50		dB
Crosstalk between channels	Vст	f = 1 MHz , V <sub>GEN</sub> = 1 V <sub>P-P</sub> , see figure 10	T <sub>A</sub> = 25°C	All	50		dB
Charge transfer error	VCTE	V <sub>S</sub> = GND, see figure 11	T <sub>A</sub> = 25°C	All		15	mV
Break-before-make time delay	reak-before-make		-55°C ≤ T <sub>A</sub> ≤ 125°C	03,04, 07	20		ns

TABLE I. Electrical performance characteristics - Continued.

Test	Symbol	Conditions  V <sub>CC</sub> = ±15 V, GND = 0 V  unless otherwise  specified	Temperature range	Device type	Lir	mits	Unit
Driver input capacitance	CA	V <sub>IN</sub> = 0 V, see 4.4.1d	T <sub>A</sub> = 25°C	All		30	pF
Switch input capacitance	C <sub>IS</sub>	See 4.4.1d, switch off	T <sub>A</sub> = 25°C	All		20	pF
Switch output capacitance	Cos	See 4.4.1d, switch off	T <sub>A</sub> = 25°C	All		20	pF

1/ The listed resistance limits correspond to the following voltage values:

75  $\Omega$  correspond to  $\pm 9.25$  V and  $\pm 6.75$  V; 150  $\Omega$  correspond to  $\pm 8.50$  V and  $\pm 6.0$  V; see table III.

#### 4. VERIFICATION.

- 4.1 <u>Sampling and inspection</u>. Sampling and inspection procedures shall be in accordance with MIL-PRF-38535 or as modified in the device manufacturer's Quality Management (QM) plan. The modification in the QM plan shall not effect the form, fit, or function as function as described herein.
- 4.2 <u>Screening</u>. Screening shall be in accordance with MIL-PRF-38535, and shall be conducted on all devices prior to qualification and quality conformance inspection. The following additional criteria shall apply:
  - a. The burn-in test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1015 of MIL-STD-883.
  - b. Reverse bias burn-in (method 1015 of MIL-STD-883). This screen shall apply to class S only. However, regardless of device class, for devices 03, 04, and 07, an additional burn-in shall be performed with the logic level of the switch drivers opposite that used in the first burn-in. Ambient temperature (T<sub>A</sub>) shall be 125°C minimum. Duration for reverse bias test shall be 24 hours minimum for class S devices, and duration for additional burn-in (class B devices) shall be 160 hours minimum.
  - c. Interim and final electrical test parameters shall be as specified in table II, except interim electrical parameters test prior to burn-in is optional at the discretion of the manufacturer.
  - d. For class S devices, post dynamic burn-in, or class B devices, post static burn-in, electrical parameter measurements may, at the manufacturer's option, be performed separately or included in the final electrical parameter measurements.
  - e. Additional screening for space level product shall be as specified in MIL-PRF-38535.

#### MIL-M-38510/105A

TABLE II. Electrical test requirements.

AUL DDE cosos	Subgroups	(see table III)
MIL-PRF-38535 test requirements	Class S devices	Class B devices
Interim electrical parameters	1	1
Final electrical test parameters	1*, 2, 3, 9	1*, 2, 3, 9
Group A test requirements	1,2,3,(4,7)**, 9,10,11, (12,13,14)***	1,2,3,(4,7)**, 9,10,11, (12,13,14)***
Group B electrical test parameters when using the method 5005 QCI option	1,2,3 and table IV delta limits	N/A
Group C end-point electrical parameters	1,2,3 and table IV delta limits	1 and table IV delta limits
Additional electrical subgroups for group C periodic inspections	N/A	(4, 7)****
Group D end-point electrical parameters	1,2,3	1
Additional electrical subgroups for group D periodic inspections	(4,7)****	None

<sup>\*</sup>PDA applies to subgroup 1.

- 4.3 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-38535.
- 4.4 <u>Technology Conformance inspection (TCI)</u>. Technology conformance inspection shall be in accordance with MIL-PRF-38535 and herein for groups A, B, C, and D inspections (see 4.4.1 through 4.4.4).
- 4.4.1 Group A inspection. Group A inspection shall be in accordance with table III of MIL-PRF-38535 and as follows:
  - a. Tests shall be as specified in table II herein.
  - b. Subgroups 5, 6, and 8 shall be omitted.
  - c. Special subgroups shall be added to group A inspection and shall consist of group A subgroups 12, 13, and 14 as specified in table III herein. The sample size series for subgroup 12 shall be 5 with no failures allowed, for all classes. The sample size series for subgroup 13 shall be 7 for all classes. The sample size series for subgroup 14 shall be 10 for all classes
  - d. C<sub>X</sub> measurements shall be made only for initial qualification and after process or design changes which may affect capacitance measurements. Capacitance shall be measured between the designated terminal and ground at the frequency of 1 MHz. (See method 3012 of MIL-STD-883). C<sub>IS</sub> and C<sub>OS</sub> tests will be measured with the switch off (see 3.5.1).
  - e. Subgroups 4 and 7 shall be performed for initial qualification only using a sample of 5 devices for each device type submitted to group A inspection, with no failure allowed. If not more than 1 failure is found in the first sample of 5, a second sample of 5 is permitted with no further failures allowed.

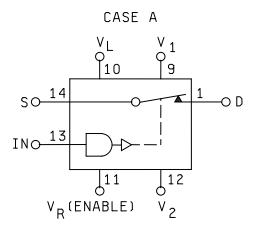
<sup>\*\*</sup> See 4.4.1e

<sup>\*\*\*</sup> See 4.4.1c

<sup>\*\*\*\*</sup> See 4.4.3c

<sup>\*\*\*\*\*</sup> See 4.4.4b

- 4.4.2 Group B inspection. Group B inspection shall be in accordance with table II of MIL-PRF-38535.
- 4.4.3 <u>Group C inspection</u>. Group C inspection shall be in accordance with table IV of MIL-PRF-38535 and as follows:
  - a. End point electrical parameters shall be as specified in table II herein.
  - b. The steady-state life test duration, test condition, and test temperature, or approved alternatives shall be as specified in the device manufacturer's QM plan in accordance with MIL-PRF-38535. The burn-in test circuit shall be maintained under document control by the device manufacturer's Technology Review Board (TRB) in accordance with MIL-PRF-38535 and shall be made available to the acquiring or preparing activity upon request. The test circuit shall specify the inputs, outputs, biases, and power dissipation, as applicable, in accordance with the intent specified in test method 1005 of MIL-STD-883. For device types 03, 04, and 07, life test duration shall be divided equally between forward bias and reverse bias.
  - c. A special subgroup shall be added to group C inspection for class B devices only, and it shall consist of the group A subgroups 4 and 7 as specified in table III herein. This special subgroup shall be performed on each device type that is qualified from those listed in 1.2.1 herein. After initial qualification, the special subgroup shall be performed periodically on a single device type selected from those device types previously qualified. A sample of 5 devices (of the device type to be inspected) shall be chosen and submitted to test with no failures allowed. If not more than 1 failure is found in the first sample of 5, a second sample of 5 is permitted with no further failures allowed. When more than one device type is qualified, the single device type selected shall be different device type for each subsequent periodic inspection until all qualified device types have been inspected. The sequence of single device types shall be repeated to fulfill the periodic inspection requirement.
  - 4.4.4 Group D inspection. Group D inspection shall be in accordance with table V of MIL-PRF-38535.
    - a. End point electrical parameters shall be as specified in table II herein.
    - b. A special subgroup shall be added to group D inspection for class S devices only, and it shall consist of the group A subgroups 4 and 7 as specified in table III herein.
    - c. A special subgroup shall be added to group D inspection for class S devices only, and it shall consist of the group A subgroups 4 and 7 as specified in table III herein. This special subgroup shall be performed on each device type that is qualified from those listed in 1.2.1 herein. After initial qualification, the special subgroup shall be performed periodically on a single device type selected from those device types previously qualified. When more than one device type is qualified, the single device type selected shall be different device type for each subsequent periodic inspection until all qualified device types have been inspected. The sequence of single device types shall be repeated to fulfill the periodic inspection requirements.
  - 4.5 Methods of inspection. Methods of inspection shall be specified and as follows.
- 4.5.1 <u>Voltage and current</u>. All voltage values given are referenced to the microcircuit ground terminals. Currents given are conventional current and positive when flowing into the referenced terminal.



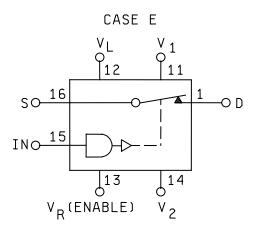
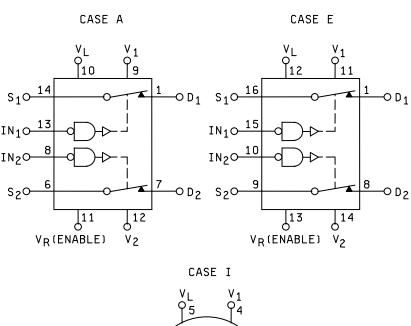


Figure 1. Terminal connection.



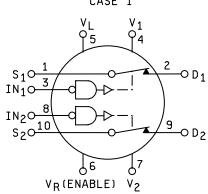
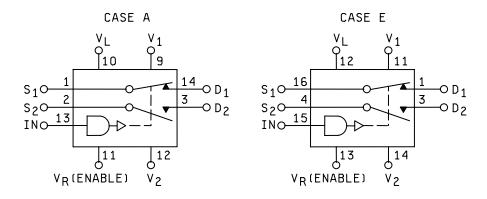


Figure 1. <u>Terminal connection</u> – continued.



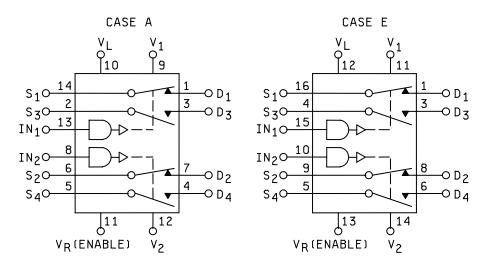
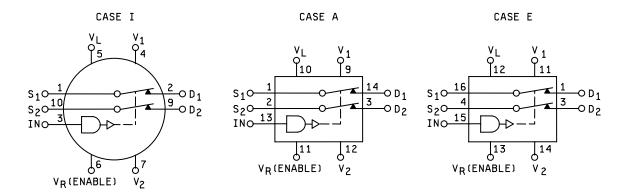


Figure 1. <u>Terminal connections</u> – Continued.



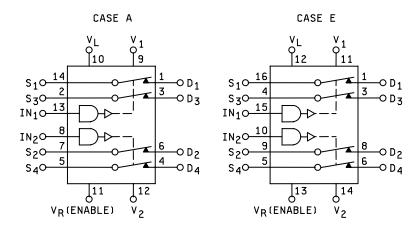
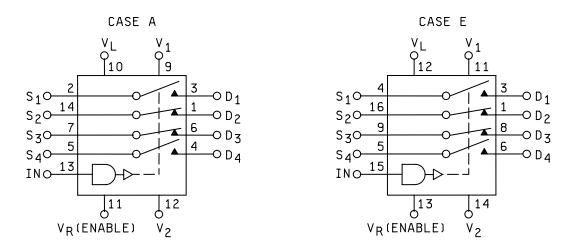


Figure 1. <u>Terminal connections</u> – Continued.



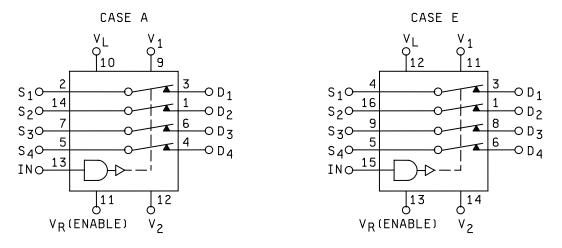
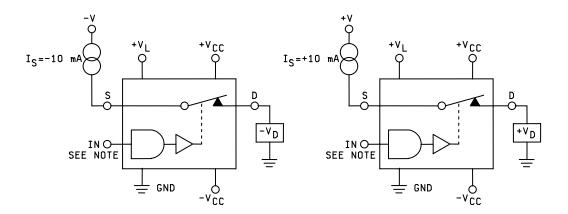


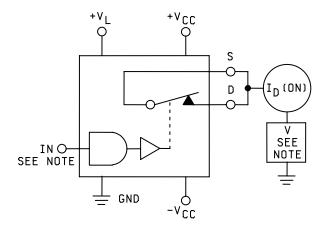
Figure 1. <u>Terminal connections</u> – Continued.



NOTE:  $V_{IN}$  from table I,  $R_{DS} = (V_S - V_D) / -10 \text{ mA}$ 

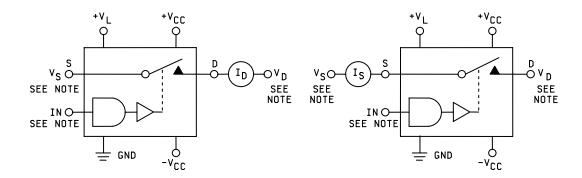
NOTE:  $V_{IN}$  from table I,  $R_{DS} = (V_S - V_D) / 10 \text{ mA}$ 

Figure 2. R<sub>DS</sub> test circuit.



NOTE: Conditions are from table I.

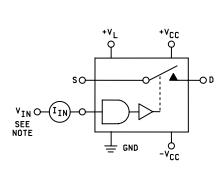
Figure 3.  $I_{D(on)}$  test circuit.

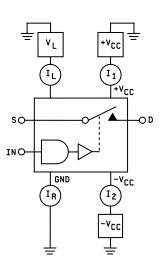


NOTE: Test conditions are from table I.

FIGURE 4.  $I_{D(off)}$  test circuit.

FIGURE 5. IS(off) test circuit.

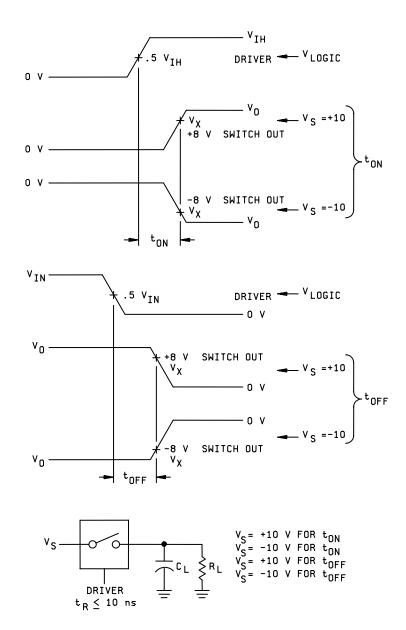




NOTE: Test conditions are from table I.

FIGURE 6.  $I_{\text{IL}},\,I_{\text{IH}}$  test circuit.

FIGURE 7. I+, I- test circuit.



 $R_L = 1 \text{ k}\Omega \pm 5 \%$ .

C<sub>L</sub> = 95 pF minimum to 200 pF maximum (includes test jig capacitance).

FIGURE 8. Input output waveforms for time delay tests.

### NOTES:

- 1. The logic driver shall have the following characteristics:
  - a.  $V_{LOGIC} = 0 V \text{ to } +3 V \text{ for device types } 01 \text{ through } 08.$
  - b. Rise time ( 0.3 V to 2.7 V )  $\leq$  10 ns for device types 01 through 08. Fall time ( 2.7 V to 0.3 V )  $\leq$  10 ns for device types 01 through 08.
- 2. See 3.5.1 for appropriate switching conditions.
- 3.  $V_{SOURCE}(V_S) = +10 \text{ V} \text{ and } -10 \text{ V} \text{ for } t_{ON}$ .
  - VSOURCE (Vs) = +10 V and -10 V for toff.
- 4.  $V_X = +8 \text{ V for } +10 \text{ V condition in (3), above.}$ 
  - $V_X = -8 \text{ V for } -10 \text{ V condition in (3), above.}$

FIGURE 8. <u>Input output waveforms for time delay tests</u> – Continued.

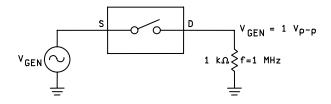


FIGURE 9. Isolation test circuit.

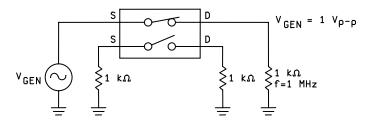


FIGURE 10. Crosstalk test circuit.

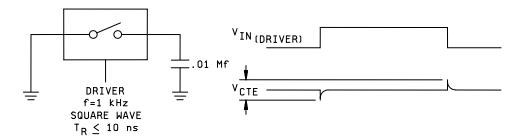
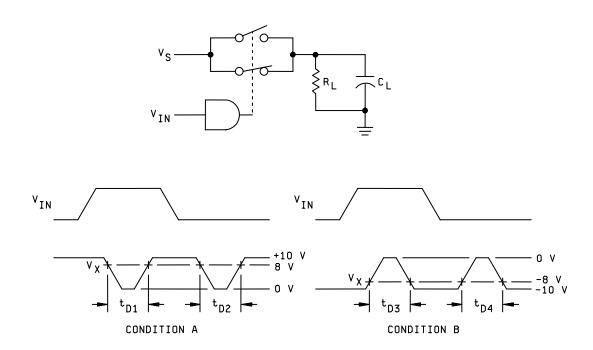


FIGURE 11. Charge transfer error test circuit.



### NOTES:

- 1.  $R_L = 1 \text{ k}\Omega \pm 5\%$ ,  $C_L = 95 \text{ pF minimum to } 200 \text{ pF maximum.}$
- 2. t<sub>D1</sub>, t<sub>D2</sub>, t<sub>D3</sub>, and t<sub>D4</sub> shall be measured. These measurements shall apply only to device types 03, 04, and 07. See 3.5.1 for switch conditions.
- 3.  $V_{SOURCE}(V_S) = +10 V$  for condition A (all device types).
  - V<sub>SOURCE</sub> (V<sub>S</sub>) = -10 V for condition B (all device types).
- 4. V<sub>X</sub> = +8 V for condition A (all device types).
  V<sub>X</sub> = -8 V for condition B (all device types).
  5. The logic driver shall have the following characteristics:
  - a. VLOGIC = 0 V to 3 V for parts 01 through 08.
  - b. Rise time  $(0.3 \text{ V to } 2.7 \text{ V}) \le 10 \text{ ns}$ , for part types 01 through 08. Fall time  $(2.7 \text{ V to } 0.3 \text{ V}) \le 10 \text{ ns}$ , for part types 01 through 08.

FIGURE 12. Break-before-make test circuit.

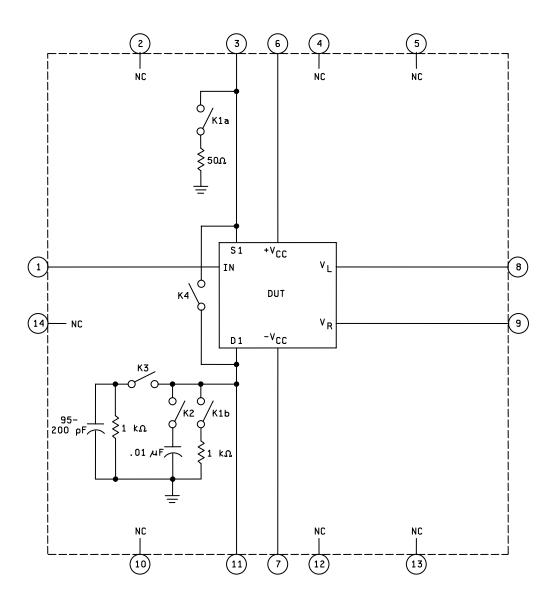


FIGURE 13. Test circuit (static and dynamic tests) for device type 01.

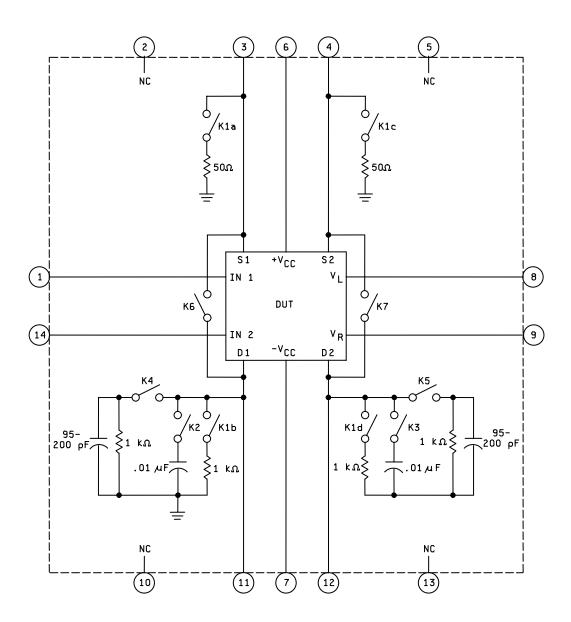


FIGURE 14. Test circuit (static and dynamic tests) for device type 02.

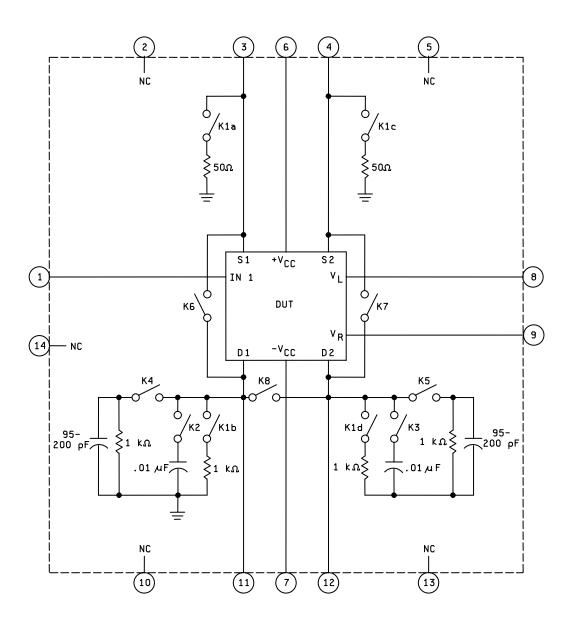


FIGURE 15. Test circuit (static and dynamic tests) for device types 03 and 05.

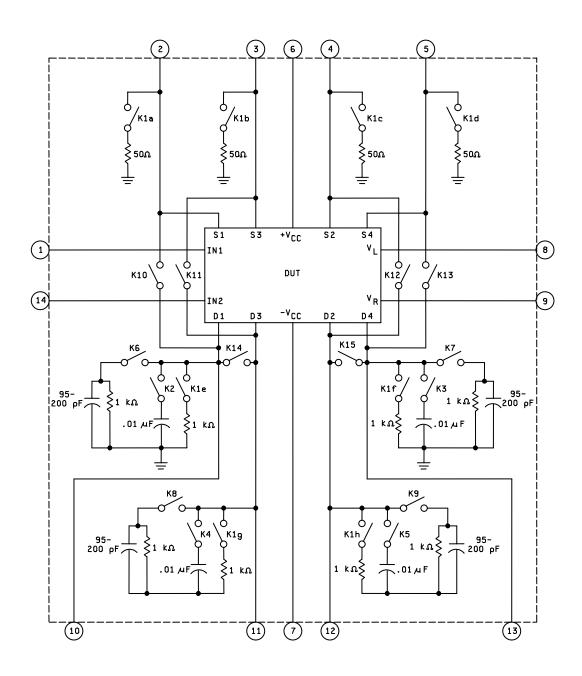


FIGURE 16. Test circuit (static and dynamic tests) for device types 04 and 06.

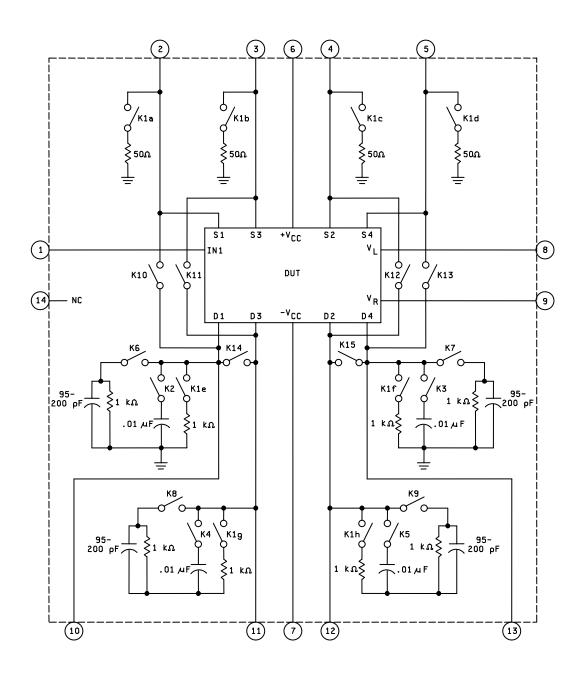


FIGURE 17. Test circuit (static and dynamic tests) for device types 07 and 08.

TABLE III. Group A inspection for device type 01.

Symbol	Test						Adapte	er pin numbe	r <u>1</u> _/							Relays	Measured pin			Test	limits			Unit
	number	IN	N.C.	S <sub>1</sub>	N.C.	N.C.	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	N.C.	D <sub>1</sub>	N.C.	N.C.	N.C.	energized	number	Subgr T <sub>A</sub> = 2			roup 2 125°C	Subgro T <sub>A</sub> = -5		Unit
		1	2	3	4	5	6	7 <sub>V</sub>	8 V	9	10	11	12	13	14			Min	Max	Min	Max	Min	Max	
R <sub>DS</sub>	1	2.4 V		10 mA			15.0 V	-15.0 V	+5.0 V	GND		-10.0 V				None	3		-9.25		-8.50		-9.25	V <u>2</u> /
"	2	"		-10 mA 10 mA			15.0 V 10.0 V	-15.0 V -10. V	"	"		10.0 V -7.5 V				"	3	9.25	-6.75	8.50	-6.0	9.25	-6.75	"
"	4	"		-10 mA			10.0 V	-10. V	"	"		7.5 V					3	6.75	-0.75	6.0	-0.0	6.75	-0.75	"
I <sub>D(ON)</sub>	5	"		10.0 V			15.0 V	-15.0 V	"	"		10.0 V				K4	3	-2	2	-200	200	-200	200	nA "
	6 7	0.8 V		-10.0 V			"		"			-10.0 V	1			K4 None	3 11	-2 -1	2	-200 -100	200 100	-200 -100	200 100	"
I <sub>D(OFF)</sub>	8	0.8 V		10.0 V			"	"	"	"		-10.0 V				None "	11	-1		-100	100	-100	100	"
I <sub>S(OFF)</sub>	9	"		-10.0 V			"	"	"	"		10.0 V					3	"	"	-100	100	-100	100	"
-(,	10	"		10.0 V			"	"	"	"		-10.0 V				"	3	"	"	-100	100	-100	100	"
I <sub>IL</sub>	11	0.0 V					"	"	"	"						"	1	-1	0	-10	0	-1	0	μА
ΙΉ	12 13	2.4 V 5.0 V						"	"	"							1	0	1	0	10 10	0	1	"
Icc	14	0.0 V	1	1				"	"	"	1		1				6		10		100		10	"
·CC	15	5.0 V						44	**	ű							6		10		100		10	"
-l <sub>CC</sub>	16	0.0 V					"	"	"	"							7	-10		-100		-10		"
	17 18	5.0 V 0.0 V					"	"	"	"					ļ		7 8	-10	10	-100	100	-10	10	"
+I <sub>L</sub>	19	5.0 V					"	"	**	"					"		8		10		100		10	"
+I <sub>R</sub>	20 21	0.0 V 5.0 V					"	"	"	"					"		9	-10 -10		-100 -100		-10 -10		"
		0.0 V	<u> </u>	I		L	1		l		1	1	I	<u> </u>	"	1	, J	Subgr	oup 4		roup 7	Subgro	up 9	
															"			$T_A = 2$			25°C	$T_A = 2$		
																	•	Min	Max	Min	Max	Min	Max	
V <sub>CTE</sub>	22	IN <u>3</u> /					15.0 V	-15.0 V	+5.0 V	GND					"	K2	11		15					mV
V <sub>CT</sub>	23	0.8 V		IN <u>4</u> /	ID (	201(1)	15.0 V	-15.0 V	+5.0 V	GND						K1	11			50	3.16			mV <sub>PP</sub> dB
V <sub>ISO</sub>	24	2.4 V		IN 4/	αB <sub>CT</sub> = -2	20 log ( V <sub>OUT</sub>	15.0 V	-15.0 V	+5.0 V	GND		1	1			K1	11		1	50	3.16			mV <sub>PP</sub>
VISO	2-7	2.7 V			dBico = -3	20 log ( V <sub>OU</sub>		10.0 V	10.0 V	OND	1					101				50	5.10			dB
t <sub>ON</sub>	25	IN		IN	ub 50 = .	0.09 ( 100	15.0 V	-15.0 V	+5.0 V	GND		OUT				КЗ	1 to 11						450	ns
toff	26	IN		IN			"	"	"	"	1	OUT	1			КЗ	1 to 11				1		250	ns
					•		•	•		•	•			•		•		Subgro		Subgr		Subgro		
																		T <sub>A</sub> = 1 Min	125°C Max	T <sub>A</sub> =	-55°C Max	T <sub>A</sub> = 2	5°C Max	
ton	27	IN		IN			15.0 V	-15.0 V	+5.0 V	GND		OUT	1	1		КЗ	1 to 11	IVIIII	550	IVIIII	IVIdX	IVIIII	IVIAX	ns
t <sub>OFF</sub>	28	IN		IN			"	"	"	"		OUT	<b>†</b>			"	"		400					"
ton	29	IN		IN			"	"	"	"	1	OUT	1				66				375		1	"
toff	30	IN		IN			"	ш	44	"		OUT				**	ш				250			"
C <sub>A</sub>	31	0.0 V					и	"	u	"						None	1						30	pF
C <sub>IS</sub>	32						"	"	"	"						"	3						20	"
Cos	33		1				"	"	"	"							11						20	"

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TABLE III. Group A inspection for device type 02.

Symbol	Test						Adapte	er pin numbe	r 1-/							Relays	Measured pin			Test	limits			
	number	IN1	N.C.	S <sub>1</sub>	2	N.C.	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	N.C.	D <sub>1</sub>	2	N.C.	IN2	energized	number		roup 1 25°C		roup 2 125°C		roup 3 -55°C	Unit
		1	2	3	4	5	6	7 <sub>V</sub>	8	9	10	11	12	13	14			Min	Max	Min	Max	Min	Max	
R <sub>DS</sub>	1 2	2.4 V		10 mA	10 mA		15.0 V	-15.0 V	+5.0 V	GND "		-10.0 V	-10.0 V		2.4 V	None "	3 4		-9.25 -9.25		-8.50 -8.50		-9.25 -9.25	V <u>2</u> /
"	3 4 5	2.4 V 2.4 V		-10 mA 10 mA	-10 mA		" 10.0 V	-10.0 V	"	"		10.0 V -7.5 V	10.0 V		2.4 V	"	3 4 3	9.25 9.25	-6.75	8.50 8.50	-6.0	9.25 9.25	-6.75	"
"	6 7 8	2.4 V		-10 mA	10 mA -10 mA		4	"	"	"		7.5 V	-7.5 V 7.5 V		2.4 V 2.4 V	14 14	4 3 4	6.75 6.75	-6.75	6.0 6.0	-6.0	6.75 6.75	-6.75	"
I <sub>D(ON)</sub>	9	2.4 V		10.0 V	10.0 V		15.0 V	-15.0 V	u	u u		10.0 V	10.0 V		2.4 V	K6 K7	3 4	-2	2	-200	200	-200	200	nA "
" "	11 12 13	2.4 V 0.8 V		-10.0 V	-10.0 V		"	"	u	"		-10.0 V	-10.0 V		2.4 V	K6 K7 None	3 4 11	-1	" 1	-100	100	-100	100	" nA
I <sub>D(OFF)</sub>	14 15	0.8 V		10.0 V	-10.0 V			"	"	"		-10.0 V	10.0 V		0.8 V	"	12 11 12		"	"	"	"	"	"
I <sub>S(QFF)</sub>	16 17 18	0.8 V		-10.0 V	10.0 V		es es	"	u	"		10.0 V	-10.0 V		0.8 V	None "	3 4	-1	1 "	-100	100	-100	100	nA "
"	19 20	0.8 V		10.0 V	10.0 V		4	"	"	"		-10.0 V	-10.0 V		0.8 V	u u	3 4	"	"	"	u u	"	"	"
I <sub>IL</sub>	21 22 23	0.0 V 2.4 V					u	"	"	"					0.0 V	14	1 14 1	-1 -1 0	0 0 1	-10 -10 0	0 0 10	-1 -1 0	0 0	μA "
"	24 25 26	5.0 V					"	« «	"	66 66					2.4 V 5.0 V	66 66	14 1 14	0	1 1	0 0	10 10 10	0	1 1	es es
+I <sub>CC</sub>	27 28	0.0 V 5.0 V					u	u	u	"					0.0 V 5.0 V	66 66	6		10 10		100 100		10 10	"
-l <sub>c</sub> c	29 30 31	0.0 V 5.0 V 0.0 V					"	"		"					0.0 V 5.0 V 0.0 V	16 16	7 7 8	-10 -10	  10	-100 -100	100	-10 -10		"
+I <sub>L</sub> " +I <sub>R</sub>	32 33	5.0 V 0.0 V					u	ш	ш	и					5.0 V 0.0 V		8 8 9	-10	10	-100	100	 0	10 10 	"
""	34	5.0 V					"	"	ш	и					5.0 V	es .	9		 roup 4 25°C	-100 Subgi			 roup 9 25°C	"
																		Min	Max	Min	Max	Min	Max	•
V <sub>CTE</sub>	35 36	IN <u>3</u> /					15.0 V "	-15.0 V "	+5.0 V	GND "					IN <u>3</u> /	K2 K3	11 12		15 15					mV "
V <sub>CT</sub>	37	0.8 V			dB <sub>CT</sub> = -20	) log ( V <sub>OUT</sub>		-15.0 V	+5.0 V	GND					2.4 V	K1	12			50	3.16			mV <sub>PP</sub> dB
V <sub>ISO</sub>	38 39	2.4 V		IN <u>4</u> /	IN <u>4</u> /	0 log ( V <sub>OUT</sub>	15.0 V 15.0 V	-15.0 V -15.0 V	+5.0 V +5.0 V	GND GND					2.4 V	K1 K1	11 12			50	3.16 3.16			mV <sub>PP</sub>
t <sub>ON</sub>	40 41	IN		IN	IN	o log ( vout	15.0 V	-15.0 V	+5.0 V	GND "		OUT	OUT		IN	K4 K5	1 to 11 14 to 12			30			450 450	ns "
t <sub>OFF</sub>	42 43	IN		IN	IN		u	"	u	u u		OUT	OUT		IN	K4 K5	1 to 11 14 to 12						250 250	ns "

TABLE III. Group A inspection for device type 02. – Continued.

Symbol	Test		Adapter pin number <sub>1</sub> _/														Measured pin			Test	limits			
	number		N.C.	S <sub>1</sub>	2	N.C.	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	N.C.	D <sub>1</sub>	2	N.C.	IN2	Relays energized	number		oup 10 125°C	Subgroup 11 T <sub>A</sub> = -55°C		Subgroup 12 T <sub>A</sub> = 25°C		Unit
		1	2	3	4	5	6	7	8	9	10	11	12	13	14			Min	Max	Min	Max	Min	Max	
t <sub>ON</sub>	44	<sup>1</sup> IN		IN C			15.0 V	-15.0 W	+5.0 V	GND		OUT				K4	1 to 11		550					ns
66	45			'n	IN		**	"	" V	"		U	OUT		IN	K5	14 to 12		550					66
t <sub>OFF</sub>	46	IN		IN			44	"	"	"		OUT				K4	1 to 11		400					"
44	47				IN		44	"	"	"			OUT		IN	K5	14 to 12		400					44
t <sub>ON</sub>	48	IN		IN			44	"	"	"		OUT				K4	1 to 11				375			"
"	49				IN		44	"	"	"			OUT		IN	K5	14 to 12				375			"
toff	50	IN		IN			"	"	"	"		OUT				K4	1 to 11				250			44
"	51				IN		44	"	"	"			OUT		IN	K5	14 to 12				250			"
C <sub>A</sub>	52	0.0 V					44	"	"	"						None	1						30	pF
**	53							"	"	"					0.0 V	"	14						30	
C <sub>IS</sub>	54							"	"							"	3						20	ш
"							и	**	"	"						"	4						20	ш
Cos	56						44	"	"	"						"	11						20	"
44	57						и	"	"	"						"	12						20	"

TABLE III. Group A inspection for device types 03, 05.

Symbol	Test								Adap	oter pin num	ber <sub>1-</sub> /						Relays	Measured pin			Test	limits			
	number		IN	N.C.	S <sub>1</sub>	2	N.C.	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	N.C.	D <sub>1</sub>	2	N.C.	N.C.	energized	number	Subgr T <sub>A</sub> =			roup 2 125°C	Subgr T <sub>A</sub> = -		Unit
		1 <u>6</u> /	1 <u>7</u> /	2	3	4	5	6	7	8	9	10	11	12	13	14			Min	Max	Min	Max	Min	Max	
RDS "	1 IN 2 3 4 5 6 7	0.8 V 2.4 V 0.8 V 2.4 V 0.8 V 2.4 V 0.8 V	2.4 V		10 mX -10 mA 10 mA	10 mA -10 mA 10 mA -10 mA		15.0 V " " 10.0 V	-15.0 V	+5.0 V	GND " " " "		-10.0 ♥ 10.0 V -7.5 V	-10.0 V 10.0 V -7.5 V 7.5 V			None " " "	4 3 4 3 4 3 4	9.25 9.25 6.75	-9.25 -9.25 -6.75 -6.75	8.50 8.50	-8.50 -8.50 -6.0 -6.0	9.25 9.25 6.75	-9.25 -9.25 -6.75 -6.75	V <u>2</u> / " " "
"	8	2.4 V	"		-10 mA			"	"	"	"		7.5 V				"	3	6.75		6.0		6.75		"
I <sub>D(ON)</sub>	9 10 11 12	0.8 V 2.4 V 0.8 V 2.4 V	"		10.0 V -10.0 V	10.0 V -10.0 V		15.0 V	-15.0 V	"	"		10.0 V -10.0 V	10.0 V -10.0 V			K7 K6 K7 K6	4 3 4 3	-2 "	2 "	-200 "	200	-200 "	200	nA "
I <sub>D(OFF)</sub>	13 14 15 16	0.8 V 2.4 V 0.8 V 2.4 V	0.8 V "		-10.0 V	-10.0 V		er er	44 44	"	"		10.0 V -10.0 V	10.0 V -10.0 V			None "	11 12 11 12	-1 " "	1 "	-100 "	100	-100 "	100	nA "
Is(OFF)	17 18 19 20	0.8 V 2.4 V 0.8 V 2.4 V	" "		-10.0 V	-10.0 V 10.0 V		11 11	44 44	"	" "		10.0 V -10.0 V	10.0 V -10.0 V			None "	3 4 3 4	-1 "	1 "	-100	100	-100 "	100	nA "
IIL	21	0.0 V	0.0 V					"	"	"	"						"	1	-1	0	-10	0	-1	0	μА
Ĕ.	22 23	2.4 V 5.0 V	2.4 V 5.0 V					"	"	"	"							1 1	0	1	0	10 10	0	1	"
+I <sub>CC</sub>	24 25	0.0 V 5.0 V	0.0 V 5.0 V					"	"	u	"						"	6 6		10 10		100 100		10 10	"
-l <sub>cc</sub>	26 27	0.0 V 5.0 V	0.0 V 5.0 V					"	"	"	"						"	7 7	-10 -10		-100 -100		-10 -10		"
+1_	28 29	0.0 V 5.0 V	0.0 V 5.0 V					66	"	"	66						ss ss	8 8		10 10		100 100		10 10	"
+I <sub>R</sub>	30 31	0.0 V 5.0 V	0.0 V 5.0 V					66	66 66	es es	66						ш	9	-10 -10		-100 -100		-10 -10		u

TABLE III. Group A inspection for device types 03, 05 – Continued.

Symbol	Test							Adap	pter pin num	ber <sub>1</sub> _/						Relays	Measured pin				limits			
	number		N.C.	S <sub>1</sub>	2	N.C.	+V <sub>CC</sub>	-V <sub>cc</sub>	L	R	N.C.	D <sub>1</sub>	2	N.C.	NC	energized	number		roup 4 25°C		roup 7 : 25°C	Subgi T <sub>A</sub> =	roup 9 25°C	Unit
		1	2	3	4	5	6	7	8	9	10	11	12	13	14			Min	Max	Min	Max	Min	Max	
V <sub>CTE</sub>	32 IN 33	IN <u>3</u> / IN 3/		GND S	GND		15.0 V	-15.0 W	+5.0 V " V	GND "		D				K2 K3	11 12		15 15					mV "
V <sub>CT</sub>	34	2.4 V		IN <u>4</u> /	dBcr = 20	log ( V <sub>OUT</sub> /	VIN )									K1	12			50	3.16			mV <sub>PP</sub> dB
V <sub>ISO</sub>	35 36	2.4 V 0.8 V		IN <u>4</u> /	IN <u>4</u> /	9 ( 100)	15.0 V 15.0 V	-15.0 V -15.0 V	+5.0 V +5.0 V	GND GND						K1 K1	12 11				3.16 3.16			mV <sub>PP</sub>
				-	$dB_{ISO} = -2$	0 log ( V <sub>OUT</sub>														50				dB
t <sub>ON</sub>	37 38	IN "		IN	IN		15.0 V "	-15.0 V "	+5.0 V	GND "		OUT	OUT			K4 K5	11 12						450 450	ns "
t <sub>OFF</sub>	39 40	IN "		IN	IN		"	"	"	"		OUT	OUT			K4 K5	11 12						250 250	"
																			oup 10 125°C		oup 11 -55°C	Subgro	oup 12 25°C	
								,			,	,						Min	Max	Min	Max	Min	Max	<u> </u>
t <sub>ON</sub>	41 42	IN "		IN	IN		15.0 V	-15.0 V	+5.0 V	GND "		OUT	OUT			K4 K5	11 12		550 550					ns "
toff	43 44	IN "		IN	IN		"	"	"	"		OUT	OUT			K4 K5	11 12		400 400					"
t <sub>ON</sub>	45 46	IN "		IN	IN		"	"	"	"		OUT	OUT			K4 K5	11 12				375 375			"
t <sub>OFF</sub>	47 48	IN "		IN	IN		"	"	"	"		OUT	OUT			K4 K5	11 12				250 250			"
CA	49	0.0 V					u u	u	"	u						None	1				200		30	pF
C <sub>IS</sub>	50 51						"	"	44	**						44	3 4						20 20	"
C <sub>OS</sub>	52 53						"	"	"							**	11 12						20 20	"
			•			,	•						•			•			oup 13 25°C	T <sub>A</sub> =	oup 14 125°C	Subgro	oup 14 -55°C	
+- /	54	IN	1	IN	IN	1	15.0 V	-15.0 V	+5.0 V	GND	1	1	1	ı	ı	K4, K8	11	Min 20	Max	Min	Max	Min	Max	ns
t <sub>D 5</sub> _/	55	"		iiN "			15.0 V	"	+3.0 V	*						**	12	20						"
t <sub>D 5</sub> _/	56 57	"			"			"	"	"						44	11 12			20 20				"
t <sub>D 5</sub> _/	58 59	"			"			"	"	44						"	11 12					20 20		"

TABLE III. Group A inspection for device types 04, 06.

Symbol	Test							Adap	ter pin numb	per 1_/								Relays	Measured			Test				
	number		IN1	S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	IN2	IN2	energized	pin	Subgi T <sub>A</sub> =	roup 1 25°C	Subgr T <sub>A</sub> = 1		Subgi T <sub>A</sub> =	oup 3 -55°C	Unit
	IN	1 <u>8</u> /	1 <u>9</u> /	2	3	4	5	6	7	8	9	10	11	12	13	14 <u>8</u> /	14 <u>9</u> /		number	Min	Max	Min	Max	Min	Max	
R <sub>DS</sub>	1 2 3	2.4 V 2.4 V	2.4 V 0.8 V	10.0 mgA	S 10.0 mA	S 10.0 mA		15.0 V	-15.0 V	+5.0 <b>∀</b>	GNDD	-10.0 bj	-10.0 V	-10.0 V		2.4 V	2.4 V	None "	2 3 4		-9.25 -9.25 -9.25		-8.50 -8.50 -8.50		-9.25 -9.25 -9.25	V <u>2</u> /
	4 5 6 7	2.4 V 2.4 V	2.4 V 0.8 V	-10.0 mA	-10.0 mA	-10.0 mA	10.0 mA	"	"	"	"	10.0 V	10.0 V	10.0 V	-10.0 V	2.4 V 2.4 V	0.8 V 2.4 V	66 66 66	5 2 3 4	9.25 9.25 9.25	-9.25	8.50 8.50 8.50	-8.50	9.25 9.25 9.25	-9.25	"
"	8 9 10	2.4 V 2.4 V	2.4 V 0.8 V	10.0 mA	10.0 mA		-10.0 mA	10.0 V	-10.0 V	« «	u	-7.5 V	-7.5 V		10.0 V	2.4 V	0.8 V	66 66	5 2 3	9.25	-6.75 -6.75	8.50	-6.0 -6.0	9.25	-6.75 -6.75	"
"	11 12 13 14	2.4 V 2.4 V	2.4 V 0.8 V	-10.0 mA	-10.0 mA	10.0 mA	10.0 mA	"		"	u	7.5 V	7.5 V	-7.5 V	-7.5 V	2.4 V 2.4 V	2.4 V 0.8 V		4 5 2 3	6.75 6.75	-6.75 -6.75	6.0 6.0	-6.0 -6.0	6.75 6.75	-6.75 -6.75	"
"	15 16					-10.0 mA	-10.0 mA	"	"	"				7.5 V	7.5 V	2.4 V 2.4 V	2.4 V 0.8 V	"	4 5	6.75 6.75		6.0 6.0		6.75 6.75		"
I <sub>D(ON)</sub>	17 18 19	2.4 V 2.4 V	2.4 V 0.8 V	10.0 V	10.0 V	10.0 V		15.0 V	-15.0 V ""	4. 4.	"	10.0 V	10.0 V	10.0 V		2.4 V	2.4 V	K10 K11 K12	2 3 4	-2	2	-200	200	-200	200	nA "
"	20 21 22 23	2.4 V 2.4 V	2.4 V 0.8 V	-10.0 V	-10.0 V	-10.0 V	10.0 V	u u	ш	4.	"	-10.0 V	-10.0 V	-10.0 V	10.0 V	2.4 V 2.4 V	0.8 V 2.4 V	K13 K10 K11 K12	5 2 3 4	"	4	« «	u u	« «	u	"
"	24 25	0.8 V	0.8 V	-10.0 V		10.0 V	-10.0 V	"	"	"	44	10.0 V		10.0 ¥	-10.0 V	2.4 V	0.8 V	K13 None	5	-1	1	-100	100	-100	100	nA
ID(OFF)	26 27 28	0.8 V	2.4 V	-10.0 V	-10.0 V	-10.0 V	-10.0 V	"« «	и и	654 654 654	44 44	10.0 V	10.0 V	10.0 V	10.0 V	0.8 V 0.8 V	0.8 V 2.4 V	" "	11 12 13	"" ""	"	-100	"	-100 ""	"	"
	29 30 31	0.8 V 0.8 V	0.8 V 2.4 V	10.0 V	10.0 V	10.0 V				"	и	-10.0 V	-10.0 V	-10.0 V		0.8 V	0.8 V	66 66 66	10 11 12	66 66	44			"	ш	"
I <sub>S(OFF)</sub>	32 33 34	0.8 V 0.8 V	0.8 V 2.4 V	-10.0 V	-10.0 V		10.0 V	15.0 V	-15.0 V	+5.0 V	GND "	10.0 V	10.0 V		-10.0 V	0.8 V	2.4 V	None "	13 2 3	-1	1 "	-100	100	-100	100	nA "
"	35 36 37	0.8 V	0.8 V	10.0 V	-10.0 V	-10.0 V	-10.0 V	"		4. 4.	"	-10.0 V	10.0 V	10.0 V	10.0 V	0.8 V 0.8 V	0.8 V 2.4 V	"	5 2	""	44 44	"	"	" " "	u u	"
"	38 39 40	0.8 V	2.4 V	10.0 1	10.0 V	10.0 V	10.0 V		u	u		10.0 1	-10.0 V	-10.0 V	-10.0 V	0.8 V 0.8 V	0.8 V 2.4 V	66	3 4 5	"		"	u u	"		"
I <sub>IL</sub>	41 42	0.0 V	0.0 V					4	4	44 154	"					0.0 V	0.0 V	44	1 14	-1 -1	0	-10 -10	0	-1 -1:	0	μ <b>A</b> "
ΙΉ	43 44	2.4 V	2.4 V					"	"	44	"					2.4 V	2.4 V	"	1 14	0°	1	0	10 10	O"	1	"
"	45 46	5.0 V	5.0 V					"	"	"	4					5.0 V	5.0 V	44	1 14	0	1	0	10 10	0	1	
+lcc "	47 48	0.0 V 5.0 V	0.0 V 5.0 V					u	"	"						0.0 V 5.0 V	0.0 V 5.0 V	"	6 6		10 10		100 100		10 10	u
-I <sub>CC</sub>	49 50	0.0 V 5.0 V	0.0 V 5.0 V					u	"	"	"					0.0 V 5.0 V	0.0 V 5.0 V	"	7 7	-10 -10		-100 -100		-10 -10		"
+I <sub>L</sub>	51 52	0.0 V 5.0 V	0.0 V 5.0 V					u	"	"	"					0.0 V 5.0 V	0.0 V 5.0 V	44	8 8		10 10		100 100		10 10	es
+I <sub>R</sub>	53 54	0.0 V 5.0 V	0.0 V 5.0 V					u	"	n.	"					0.0 V 5.0 V	0.0 V 5.0 V	"	9	-10 -10		-100 -100		-10 -10	-	

TABLE III. Group A inspection for device types 04, 06 – Continued.

Symbol	Test							Adap	ter pin number	1-/						Relays	Measured			Test li	nits			
	number		S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	IN2	energized	pin	Subgi T <sub>A</sub> =	roup 4 25°C					Unit
	Ī	1	2	3	4	5	6	7	8	9	10	11	12	13	14		number	Min	Max					
V <sub>CTE</sub>	<sup>55</sup> IN1 56	IN <u>3</u> / IN <u>3</u> /	GNDS	S GND	S		15.0 V	-15.0 V	+5.0 ₹	GND <sub>D</sub>	D	D	D			K2 K4	10 11		15					mV "
"	57	114 <u>3</u> /		GND	GND	OND	"	"	"	"					IN <u>3</u> / IN <u>3</u> /	K5	12							"
	58					GND						l .			IN <u>3</u> /	K3	13	Subgr		Subgro		Subgro		
																		T <sub>A</sub> =	25°C Max	T <sub>A</sub> = 2 Min	5°C Max	T <sub>A</sub> = 1 Min	25°C Max	
V <sub>CT</sub>	59	2.4 V	IN <u>4</u> /				15.0 V	-15.0 V	+5.0 V	GND "						K1	12	"	3.16	IVIIII	IVIGA	101111	IVIGA	mV <sub>PP</sub>
"	60				IN <u>4</u> / dB <sub>CT</sub> = -20	log ( Vout	[ " /V <sub>IN</sub> )	"	"	l "					2.4 V	K1	10	50	3.16					ďB
V <sub>ISO</sub>	61	0.8 V	IN <u>4</u> /	151 47		3 ( 001	15.0 V	-15.0 V	+5.0 V	GND "						K1	10		3.16					mV <sub>PP</sub>
"	62 63	0.8 V		IN <u>4</u> /	IN <u>4</u> /		"	"	"	"					0.8 V	K1 K1	11 12		3.16 3.16					"
"	64				$dB_{ISO} = -2$	IN <u>4</u> / 0 log ( V <sub>OUT</sub>	/ V <sub>IN.</sub> )	"	"	"					0.8 V	K1	13	50	3.16					dB
ton	65	IN	IN		150 -	3 ( 301	15.0 V	-15.0 V	+5.0 V	GND "	OUT	OUT				K6	2 to 10				450			ns "
"	66 67	IN		IN	IN		"	"	"	"		OUT	OUT		IN	K8 K9	3 to 11 4 to 12				450 450			"
t <sub>OFF</sub>	68 69	IN	IN			IN	15.0 V	-15.0 V	+5.0 V	" GND	OUT			OUT	IN	K7 K6	5 to 13 2 to 10				450 250			"
-OFF	70 71	IN		IN	IN		"	"	"	"		OUT	OUT		IN	K8 K9	3 to 11 4 to 12				250 250			"
"	72				IIN	IN	и	u	и	и			001	OUT	IN IN	K7	5 to 13				250 250			"
t <sub>ON</sub>	73 74	IN IN	IN	IN			15.0 V	-15.0 V	+5.0 V	GND "	OUT	OUT				K6 K8	2 to 10 3 to 11						550 550	ns "
"	75 76				IN	IN	"	"	"	"		00.	OUT	OUT	IN IN	K9 K7	4 to 12 5 to 13						550 550	"
t <sub>OFF</sub>	77	IN	IN			liv.	15.0 V	-15.0 V	+5.0 V	GND	OUT			001	IIN	K6	2 to 10						400	"
"	78 79	IN		IN	IN		"	"	"	"		OUT	OUT		IN	K8 K9	3 to 11 4 to 12						400 400	"
"	80					IN	"	"	"	"				OUT	IN	K7	5 to 13	Subgro	oup 11	Subgrou	ın 12	Subgro	400	"
																		T <sub>A</sub> =		T <sub>A</sub> = 2		$T_A = 1$	25°C	
ton	81	IN	IN				15.0 V	-15.0 V	+5.0 V	GND	OUT					K6	2 to 10	Min 	375	Min	Max	Min	Max	ns
"	82 83	IN		IN	IN		"	"	"	"		OUT	OUT		IN	K8 K9	3 to 11 4 to 12		375 375					"
"	84					IN	45.01/	45.01/	"	" OND	OUT			OUT	IN	K7	5 to 13		375					"
t <sub>OFF</sub>	85 86	IN IN	IN	IN			15.0 V	-15.0 V	+5.0 V	GND "	OUT	OUT				K6 K8	2 to 10 3 to 11		250 250					"
"	87 88				IN	IN	"	"	"	"			OUT	OUT	IN IN	K9 K7	4 to 12 5 to 13		250 250					"
C <sub>A</sub>	89 90	0.0 V					"	"	"	"					0.0 V	None "	1 14				30 30			pF "
C <sub>IS</sub>	91						ű	ш	ű	"					0.0 V	"	2				20			"
"	92 93						"	"	"	"						"	3 4				20 20			"
"	94 95						"	"	"	"						"	5 10				20			"
C <sub>OS</sub>	96						"	"	"	"						"	11				20			"
	97 98						"	u u	"	"						"	12 13				20 20			"
t <sub>D 5</sub> _/	99 100	IN IN	IN IN	IN IN			"	"	"	"						K6, K14 K6, K14	10 11					20		ns "
	101	IIN	IIN	IIN	IN IN	IN	"	"	"	"					IN IN	K7, K15	12					20 20 20		"
	102		l		IN	IN			*			l			IN	K7, K15	13		L			20		ــــــــــا

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TABLE III. Group A inspection for device types 04, 06 – Continued.

Symbol	Test							Adap	ter pin numb	er <u>1</u> /						Relays	Measured			Test	limits		Unit
	number	IN1	S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	IN2	energized	pin		oup 14 125°C		roup 14 -55°C		
		1	2	3	4	5	6	7	8	9	10	11	12	13	14		number	Min	Max	Min	Max		1
t <sub>D 5</sub> _/	103 104 105 106	IN IN	IN S	IN S	S IN IN	IN IN	15.0 V	-15.0 V <sub>V</sub>	+5.0 V	GND " D	D	D	D		IN IN	K6, K14 K6, K14 K7, K15 K7, K15	10 11 12 13	20 20 20 20 20	  				ns "
t <sub>D 5</sub> _/	107 108 109 110	IN IN	IN IN	IN IN	IN IN	IN IN	66 66 66	и и	66 66	u u					IN IN	K6, K14 K6, K14 K7, K15 K7, K15	10 11 12 13			20 20 20 20 20			64 64 64

TABLE III. Group A inspection for device type 07, 08.

									Aua	oter pin num	ber 1_/						Relays	Measured				limits			J
	number		IN	S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	N.C.	energized	pin	Subgi T <sub>A</sub> =		Subgi T <sub>A</sub> =	roup 2 125°C	Subgr T <sub>A</sub> = -		Unit
		1 10/	1 <u>11</u> /	2	3	4	5	6	7	8	9	10	11	12	13	14	1	number	Min	Max	Min	Max	Min	Max	
R <sub>DS</sub>	1 1	2.4 V	0.8 V	10.0 mgA		S		15.0 V	-15.0 W	+5.0 V,	GND <sub>"</sub>	-10.0 Ŋ	_	_			None	2		-9.25		-8.50		-9.25	V <u>2</u> /
	2	"	2.4 V	0	10.0 mA			**	"	" V	" D		-10.0 ₹	D			"	3		-9.25		-8.50		-9.25	"
	3		2.4 V 0.8 V			10.0 mA	400							-10.0 V	40.01/			4 5		-9.25 -9.25		-8.50 -8.50		-9.25 -9.25	
"	4 5	"	0.8 V 0.8 V	-10.0 mA			10.0 mA	-	-			10.0 V			-10.0 V		"	5	9.25	-9.25	8.50	-8.50	0.25	-9.25	"
44	6	"	2.4 V	-10.0 IIIA	-10.0 mA				"	"	"	10.0 V	10.0 V				"	3	9.25		8.50		9.25 9.25		"
44	7	"	2.4 V		10.011174	-10.0 mA			"		44		10.0 V	10.0 V			"	4	9.25		8.50		9.25		"
44	8	"	0.8 V				-10.0 mA	44	"	"	"				10.0 V		"	5	9.25		8.50		9.25		"
**	9	"	0.8 V	10.0 mA				10.0 V	-10.0 V	"	"	-7.5 V					"	2		-6.75		-6.0		-6.75	"
**	10	"	2.4 V		10.0 mA			"	"	"	"		-7.5 V				"	3		-6.75		-6.0		-6.75	"
"	11	"	2.4 V			10.0 mA		"	"	"	"			-7.5 V				4		-6.75		-6.0		-6.75	
	12		0.8 V	4004			10.0 mA					7.51/			-7.5 V			5	0.75	-6.75		-6.0	0.75	-6.75	
	13	"	0.8 V 2.4 V	-10.0 mA	-10.0 mA	1		"		"		7.5 V	7.5 V	l				2	6.75 6.75		6.0 6.0		6.75 6.75		"
"	14 15	"	2.4 V 2.4 V		-10.0 mA	-10.0 mA		"	"	"	"		7.5 V	7.5 V			"	3 4	6.75		6.0		6.75		"
"	16	"	0.8 V			-10.0 IIIA	-10.0 mA	"	"	"	"			7.5 V	7.5 V		"	5	6.75		6.0		6.75		"
Incom	17	"	0.8 V	10.0 V		1	10.0/	15.0 V	-15.0 V	"	u	10.0 V		l			K10	2	-2	2	-200	200	-200	200	nA
I <sub>D(ON)</sub>	18	"	2.4 V	10.0 v	10.0 V			13.0 V	-13.0 V	"	"		10.0 V	l			K11	3	-		"				"
44	19	"	2.4 V		10.0 V	10.0 V			"	"	и		10.0 V	10.0 V			K12	4	"		"		"	ш	"
**	20	"	0.8 V			10.0	10.0 V	*	"	"	"			10.0 1	10.0 V		K13	5	"	"	"	"	"	ш	"
**	21	"	0.8 V	-10.0 V					"	"	"	-10.0 V					K10	2	"	"	"	**	"	ш	"
44	22	"	2.4 V		-10.0 V			44	"	"	"		-10.0 V				K11	3	"		"	"	"	"	"
**	23	"	2.4 V			-10.0 V			"	"	"			-10.0 V			K12	4	"	**	"	"	"	"	"
	24		0.8 V				-10.0 V	-							-10.0 V		K13	5							
I <sub>D(OFF)</sub>	25	0.8 V	2.4 V	-10.0 V				"	"	"	"	10.0 V					None	10	-1	1	-100	100	-100	100	nA
"	26		0.8 V		-10.0 V			"		"	"		10.0 V	40.01/				11							
	27 28		0.8 V 2.4 V			-10.0 V	-10.0 V			"	"			10.0 V	10.0 V		"	12 13	"		"		"		"
44	29		2.4 V 2.4 V	10.0 V			-10.0 V			"	"	-10.0 V			10.0 V			10	"	"	"				"
**	30	"	0.8 V	10.0 V	10.0 V			44	44	"	"	-10.0 V	-10.0 V				"	11	"	"	"		"		"
44	31	"	0.8 V		10.0 1	10.0 V			"	"	"		10.0 1	-10.0 V			"	12	"	"	"	"	"	**	"
44	32	"	2.4 V				10.0 V	44	"	"	"				-10.0 V		"	13	"	"	"	"	"	"	"
I <sub>S(OFF)</sub>	33	"	2.4 V	-10.0 V				"	"	"	"	10.0 V					None	2	-1	1	-100	100	-100	100	nA
0(011)	34	"	0.8 V		-10.0 V			*	"	"	ıı .		10.0 V				"	3	"	"	"	"	"	"	"
"	35	"	0.8 V			-10.0 V	1	44	"	"	"		1	10.0 V			"	4	"	"	"	"	"	"	"
"	36	"	2.4 V	l		1	-10.0 V	**	"	"	"		l	l	10.0 V		"	5	"	"	"	"	"	"	"
"	37	"	2.4 V	10.0 V			1	"	"	"	"	-10.0 V					"	2	"	"	"	"	"	"	"
	38	"	0.8 V		10.0 V	40.01/				"			-10.0 V	40.01/				3			"	"	"	"	"
"	39 40	"	0.8 V 2.4 V			10.0 V	10.0 V			"				-10.0 V	-10.0 V		"	4	"	"	"	"	"	"	"
I	41	0.0 V	0.0 V			<del>                                     </del>	10.0 V	"	и	"	и			<del> </del>	-10.0 V		и	1	-1	0	-10	0	-1	0	μА
I <sub>IH</sub>	42	2.4 V	2.4 V				<del>                                     </del>	"	и	ш	и						и	1	0	1	0	10	0	1	μА "
"H	43	5.0 V	5.0 V					"	u	"	u						и	1	0	1	0	10	0	1	"
+l <sub>CC</sub>	44	0.0 V	0.0 V					ш	"	ш	и						и	6		10		100		10	"
44	45	5.0 V	5.0 V					"	ш	"	и						и	6		10		100		10	"
-I <sub>CC</sub>	46	0.0 V	0.0 V					"	"	"	"						"	7	-10		-100		-10		"
	47	5.0 V	5.0 V				1											7	-10		-100		-10		
+IL	48	0.0 V	0.0 V					"	"	"	"						"	8		10		100		10	"
11-	49 50	5.0 V 0.0 V	5.0 V 0.0 V				1				"				-	-		8	-10	10	-100	100	-10	10	
+I <sub>R</sub>	50 51	5.0 V	5.0 V					"	"	"	"						"	9 9	-10 -10		-100		-10 -10		"

TABLE III. Group A inspection for device types 07, 08 – Continued.

Symbol	Test						Adap	ter pin numbe	r <u>1</u> ./							Relays	Measured			Test I	imits			11.2
	number	IN1	S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	NC	energized	pin		roup 4 25°C					Unit
		1	2	3	4	5	6	7	8	9	10	11	12	13	14		number	Min	Max					
V <sub>CTE</sub>	52	IN <u>3</u> / IN <u>3</u> /	S	S	S		15.0 V	-15.0 V <sub>V</sub>	+5.0 V	GND <sub>D</sub>	D	D	D			K2 K4	10 11		15					mV "
"	53 54 55	IN 3/ IN 3/ IN 3/					"	"	"	"						K5 K3	12		"					
	55	IN <u>3</u> /					-									K3	13	Subg	roup 7	Subgr	oup 9		oup 10	+
																		T <sub>A</sub> =	25°C Max	T <sub>A</sub> = 2	25°C Max	T <sub>A</sub> =	125°C Max	_
V <sub>CT</sub>	56	2.4 V	IN <u>4</u> /				15.0 V	-15.0 V	+5.0 V	GND						K1	12		3.16	IVIII	3.16	IVIIII	IVIdX	mV <sub>PP</sub>
"	57	2.4 V			$dB_{CT} = -20$ IN 4/	log ( V <sub>OUT</sub>	/ V <sub>IN</sub> ) 15.0 V	-15.0 V	+5.0 V	GND						K1	10	50	3.16					dB mV <sub>PP</sub>
V <sub>ISO</sub>	58	0.8 V			111 4/		15.0 V	-15.0 V	+5.0 V	GND						K1	10		3.16					mV <sub>PP</sub>
	59 60	0.8 V 0.8 V					"	"	"	"						K1 K1	11 12		3.16 3.16					"
"	61	0.8 V			1	ļ	"	"	"	"						K1	13		3.16					"
t <sub>ON</sub>	62	IN	IN		$dB_{ISO} = -2$	20 log ( V <sub>OUT</sub>	15.0 V	-15.0 V	+5.0 V	GND	OUT					K6	2 to 10	50			450			dB ns
"	63 64	IN IN		IN	IN		"	"	"	"		OUT	OUT			K8 K9	3 to 11				450 450			"
"	65	IN			IIN	IN	ű	44	"	"			001	OUT		K7	4 to 12 5 to 13				450			"
toff	66 67	IN IN	IN	IN			15.0 V	-15.0 V	+5.0 V	GND "	OUT	OUT				K6 K8	2 to 10 3 to 11				250 250			"
"	68 69	IN			IN	IN	"	"	"	"		00.	OUT	OUT		K9 K7	4 to 12				250 250			"
ton	70	IN IN	IN			IN	15.0 V	-15.0 V	+5.0 V	GND	OUT			001		K/ K6	5 to 13 2 to 10				250		550	ns
	71 72	IN IN		IN	IN		"	"	"	"		OUT	OUT			K8 K9	3 to 11 4 to 12						550 550	"
"	73	IN				IN	"	"	"	"			001	OUT		K7	5 to 13						550	"
toff	74 75	IN IN	IN	IN			15.0 V "	-15.0 V	+5.0 V	GND "	OUT	OUT				K6 K8	2 to 10 3 to 11						400 400	
"	76 77	IN IN			IN	IN	"	"	"	"			OUT	OUT		K9 K7	4 to 12 5 to 13						400 400	"
							1	1	ı					001	I	1	0.0.10		oup 11	Subgro			oup 13	1
																		I <sub>A</sub> =	-55°C Max	T <sub>A</sub> = 2	Max	I <sub>A</sub> =	25°C Max	-
t <sub>ON</sub>	78 79	IN IN	IN	IN			15.0 V	-15.0 V	+5.0 V	GND "	OUT	OUT				K6 K8	2 to 10 3 to 11		375 375					ns "
"	80	IN		IIN	IN		"	"	"	"		001	OUT			K9	4 to 12		375					"
toff	81 82	IN IN	IN			IN	15.0 V	-15.0 V	+5.0 V	GND	OUT			OUT		K7 K6	5 to 13 2 to 10		375 250					- "
	83 84	IN IN		IN	IN		"	"	"	"		OUT	OUT			K8 K9	3 to 11 4 to 12		250 250					
*	85	IN			IIN	IN	ű	u	u	"			001	OUT		K7	5 to 13		250					и
C <sub>A</sub>	86 87	0.0 V					"	"	"	"						None "	1 2				30 20			pF "
44	88						"	"	"	"						"	3				20			"
"	89 90						"	"	"	"						"	4 5				20 20			"
Cos	91						"	"	"	"						"	10				20			"
	92 93						"	"	"	"						"	11 12				20 20			"
-	94 95	IN	IN	IN	1		"	"	"	"						" K6, K14	13 10				20	20		ns
t <sub>D 5</sub> _/	96 97	IN	IN	IN		IN.	"	44	"	"						K6, K14	11					20		"
	97 98	IN IN			IN IN	IN IN	"	4	"	"						K7, K15 K7, K15	12 13					20 20		

TABLE III. Group A inspection for device types 07, 08 - Continued.

Symbol	Test							Adap	ter pin numb	oer <u>1</u> /						Relays	Measured			Test	limits		Unit
	number	IN1	S <sub>1</sub>	3	2	4	+V <sub>CC</sub>	-V <sub>CC</sub>	L	R	1	3	2	4	IN2	energized	pin	Subgro T <sub>A</sub> = 1	oup 14 125°C		roup 14 -55°C		
		1	2	3	4	5	6	7	8	9	10	11	12	13	14		number	Min	Max	Min	Max		í '
t <sub>D 5</sub> _/	99 100 101 102	IN IN IN	IN IN S	IN IN S	S IN IN	IN IN	15.0 V	-15.0 V <sub>V</sub>	+5.0 \	GND "D	D	D	D			K6, K14 K6, K14 K7, K15 K7, K15	10 11 12 13	20 20 20 20					ns "
t <sub>D 5</sub> _/	103 104 105 106	IN IN IN IN	IN IN	IN IN	IN IN	IN IN	66 66 66	и и	"	ec ec						K6, K14 K6, K14 K7, K15 K7, K15	10 11 12 13			20 20 20 20 20	  		44 44

- 1/ The test circuits used with table III are shown in figure 13, 14, 15, 16, and 17. The waveforms of figure 8 apply to all device types as specified in table III (see tests for ton and toff). The waveforms of figure 12 apply to devices 03, 04, and 07 only as specified in table III.
- 2/ R<sub>DS</sub> may be measured differentially with respect to V<sub>A</sub>. In case of differentially measured voltages, the table III limits representing voltage drop across the tested switch must be maintained.
- 3/ The input pulse generator shall have the following characteristics: V<sub>GEN</sub> = 0-3 V for all device types: rise time / fall time ≤ 10 ns; PRR = 1 kHz at 50 percent duty cycle.
- $\underline{4}$ / The input generator shall have the following characteristics:  $V_{GEN} = 1 V_{PP}$  at 1 MHz.
- 5/ Break-before-make test applies to devices 03, 04, and 07 only.
- 6/ Conditions for device type 03 only.
- 7/ Conditions for device type 05 only.
- 8/ Conditions for device type 06 only.
- 9/ Conditions for device type 04 only.
- 10/ Conditions for device type 08 only.
- 11/ Conditions for device type 07 only.

Table IV. Groups C end point electrical parameters.  $(T_A = 25^{\circ}C, \pm V_{CC} = \pm 15 \text{ V}).$ 

		Device types 01 -	- 08
Test	Lin	nits	Delta
	Min	Max	Della
R <sub>DS</sub>	+9.25 V	-9.25 V	50 mV
R <sub>DS</sub>	-10.00 V	+10.00 V	50 mV
I <sub>S(OFF)</sub>	-1 nA	+1 nA	±0.5 nA
I <sub>D(OFF)</sub>	-1 nA	+1 nA	±0.5 nA

#### PACKAGING

5.1 <u>Packaging requirements</u>. For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When packaging of materiel is to be performed by DoD personnel, these personnel need to contact the responsible packaging activity to ascertain requisite packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activity within the Military Department of Defense Agency, or within the Military Department's System Command. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

### 6. NOTES

(This section contains information of a general or explanatory nature which may be helpful, but is not mandatory.)

- 6.1 Intended use. Microcircuits conforming to this specification are intended for logistic support of existing equipment.
- 6.2 Acquisition requirements. Acquisition documents should specify the following:
  - a. Title, number, and date of the specification.
  - b. PIN and compliance identifier, if applicable (1.2).
  - c. Requirements for delivery of one copy of the conformance inspection data pertinent to the device inspection lot to be supplied with each shipment by the device manufacturer, if applicable.
  - d. Requirements for certificate of compliance, if applicable.
  - e. Requirements for notification of change of product or process to acquiring activity in addition to notification of the qualifying activity, if applicable.
  - f. Requirements for failure analysis (including required test condition of MIL-STD-883, method 5003), corrective action and reporting of results, if applicable.
  - g. Requirements for product assurance options.
  - h. Requirements for special carriers, lead lengths, or lead forming, if applicable. These requirements should not affect the part number. Unless otherwise specified, these requirements will not apply to direct purchase by or direct shipment to the Government.
  - i. Requirements for "JAN" marking.
  - j. Packaging requirements (see 5.1).

- 6.3 <u>Qualification</u>. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List QML-38535 whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or purchase orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from DSCC-VQ, 3990 E. Broad Street, Columbus, Ohio 43123-1199.
- 6.4 <u>Superseding information</u>. The requirements of MIL-M-38510 have been superseded to take advantage of the available Qualified Manufacturer Listing (QML) system provided by MIL-PRF-38535. Previous references to MIL-M-38510 in this document have been replaced by appropriate references to MIL-PRF-38535. All technical requirements now consist of this specification and MIL-PRF-38535. The MIL-M-38510 specification sheet number and PIN have been retained to avoid adversely impacting existing government logistics systems and contractor's parts lists.
- 6.5 <u>Abbreviations, symbols, and definitions</u>. The abbreviations, symbols, and definitions used herein are defined in MIL-PRF-38535, MIL-HDBK-1331, and as follows:.

+ACC		Positive supply voltage.
-V <sub>C</sub> C		Negative supply voltage.
+lcc		Positive supply current.
-Icc		Negative supply current.
$V_L$		Logic supply voltage.
ΙL		Logic supply current.
$R_{DS}$		Resistance of an "ON" switch.
$V_{D}$		Drain voltage.
$V_S$		Source voltage.
I <sub>D(ON</sub>	)	Leakage current from an "ON" driver into the switch.
$I_{D(OF)}$	F)	Leakage current into the drain terminal of an "OFF" switch.
I <sub>S(OFI</sub>	F)	Leakage current into the source terminal of an "OFF" switch.
ton		Switching time as defined in figure 8.
tOFF		Switching time as defined in figure 8.
VCTE		Charge transfer error.
$V_{CT}$		Crosstalk between switches.
$V_{\text{ISO}}$		Isolation from source to drain of a closed switch.

- 6.6 <u>Logistic support.</u> Lead materials and finishes (see 3.4) are interchangeable. Unless otherwise specified, microcircuits acquired for Government logistic support will be acquired to device class B (see 1.2.2), lead material and finish A (see 3.4). Longer length leads and lead forming should not affect the part number.
- 6.7 <u>Substitutability</u>. The cross-reference information below is presented for the convenience of users. Microcircuits covered by this specification will functionally replace the listed generic-industry type. Generic-industry microcircuit types may not have equivalent operational performance characteristics across military temperature ranges or reliability factors equivalent to MIL-M-38510 device types and may have slight physical variations in relation to case size. The presence of this information should not be deemed as permitting substitution of generic-industry types for MIL-M-38510 types or as a waiver of any of the provisions of MIL-PRF-38535.

Military device type	Generic-industry type
01	5040
02	5041
03	5042
04	5043
05	5044
06	5045
07	5046
08	5047

### MIL-M-38510/105A

6.8 <u>Changes from previous issue</u>. Marginal notations is revision to identify changes with respect to the previous issue, due to the extensiveness of the changes.

Custodians: Preparing activity:
Army – CR
Navy - EC

Preparing activity:
DLA - CC

Air Force - 11 Project 5962-2005-056 NASA – NA DLA – CC

Review activities: Army – MI, SM Navy – AS, CG, MC, SH, TD Air Force – 03, 19, 99

NOTE: The activities listed above were interested in this document as of the date of this document. Since organizations and responsibilities can change, you should verify the currency of the information above using the ASSIST Online database at <a href="http://assist.daps.dla.mil">http://assist.daps.dla.mil</a>.